

### PNP -0.7A -80V Middle Power Transistor

Parameter	Value
$V_{CEO}$	-80V
I <sub>C</sub>	-0.7A

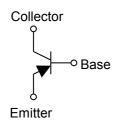
#### Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR514P
- 3) Low V<sub>CE(sat)</sub>

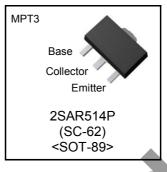
$$V_{CE(sat)} = -0.4V(Max.)$$
  
 $(I_C/I_B = -300mA/-15mA)$ 

4) Lead Free/RoHS Compliant.

## •Inner circuit



#### Outline



## Applications

Motor driver , LED driver Power supply

## Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR514P	MPT3	4540	T100	180	12	1,000	MD

## ● Absolute maximum ratings (Ta = 25°C)

Parameter		Values	Unit
Collector-base voltage		-80	V
Collector-emitter voltage		-80	V
Emitter-base voltage		-6	V
DC	I <sub>C</sub>	-0.7	А
Pulsed	I <sub>CP</sub> *1	-1.4	А
Power dissipation		0.5	W
		2.0	W
Junction temperature		150	°C
Range of storage temperature		−55 to +150	°C
	DC Pulsed	$\begin{array}{c c} & V_{CBO} \\ \hline & V_{CEO} \\ \hline & V_{EBO} \\ \hline \\ DC & I_C \\ \hline Pulsed & I_{CP}^{*1} \\ \hline & P_D^{*2} \\ \hline & P_D^{*3} \\ \hline & T_j \\ \hline \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

<sup>\*1</sup> Pw=10ms, single pulse

<sup>\*2</sup> Each terminal mounted on a reference land

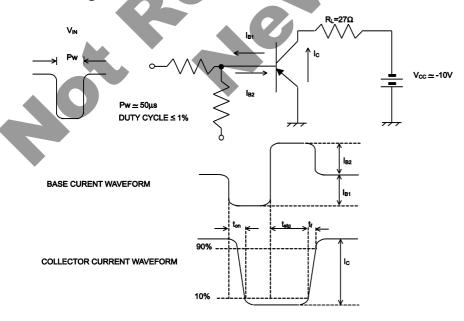
<sup>\*3</sup> Mounted on a ceramic board (40×40×0.7mm)

## ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = -1mA	-80	-	-	V
Collector-base breakdown voltage	BV <sub>CBO</sub>	$I_{C} = -100 \mu A$	-80	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	$I_E = -100 \mu A$	-6	ı	-	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -80V	ı	-	1	μА
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -4V	-	-	-1	μΑ
Collector-emitter saturation voltage	V <sub>CE(sat)</sub> *1	$I_C = -300 \text{mA}, I_B = -15 \text{mA}$		-0.20	-0.40	V
DC current gain	h <sub>FE</sub>	$V_{CE} = -3V$ , $I_{C} = -100$ mA	120	-	390	-
Transition frequency	f <sub>⊤</sub>	$V_{CE} = -10V, I_{E} = -200 \text{mA}$ f=100MH <sub>Z</sub>	-	380	-	MHz
Output capacitance	C <sub>ob</sub>	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz	-	10	-	pF
Turn-on time	t <sub>on</sub> *2	I <sub>C</sub> = -0.35A	C	50	-	ns
Storage time	t <sub>stg</sub> *2	I <sub>B1</sub> = -35mA I <sub>B2</sub> =35mA	-	350	-	ns
Fall time	t <sub>f</sub> *2	V <sub>CC</sub> <sup>≃</sup> −10V	-	50	-	ns

<sup>\*1</sup> Pulsed

# •Switching time test circuit



<sup>\*2</sup> See switching time test circuit

## ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

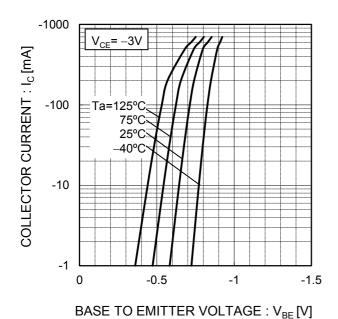
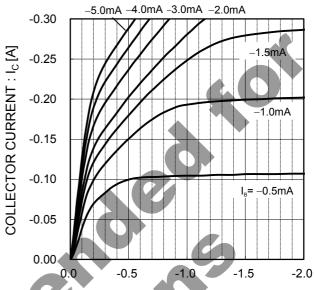


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V<sub>CE</sub> [V]

Fig.3 DC Current Gain vs. Collector Current(I)

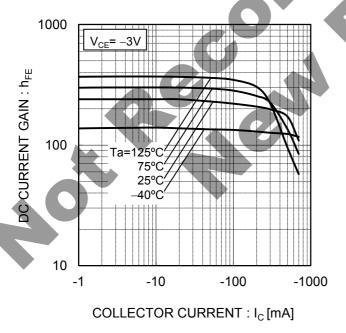
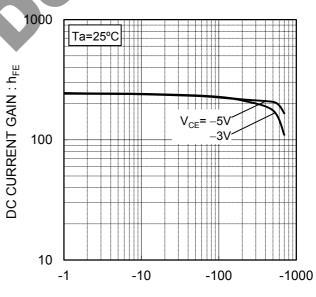


Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT :  $I_C$  [mA]

### ●Electrical characteristic curves(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage

COLLECTOR CURRENT : I<sub>C</sub> [mA]

vs. Collector Current (II)

Ta=25°C

Ta=25°C

Ta=25°C

To Ta=25°C

Fig.6 Collector-Emitter Saturation Voltage

Fig.7 Base-Emitter Saturation Voltage vs. Collector Current -10  $I_{\rm C}/I_{\rm B}=20$ BASE-EMITTER SATURATION VOLTAGE : V<sub>BE(sat)</sub> [V] Pulsed -40°C 25°C 75°C 125°C -0.1 -1 -10 -100 -1000 COLLECTOR CURRENT: Ic [mA]

Fig.8 Gain Bandwidth Product
vs. Emitter Current

1000

Ta=25°C
V<sub>CE</sub>= -10V

10

10

10

To
1000

EMITTER CURRENT: I<sub>E</sub> [mA]

## ●Electrical characteristic curves(Ta = 25°C)

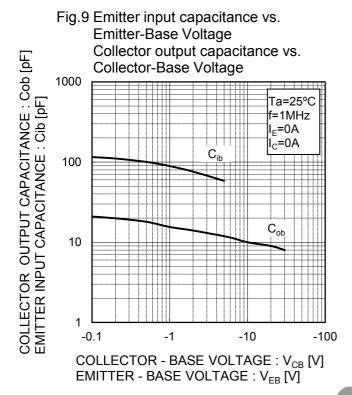
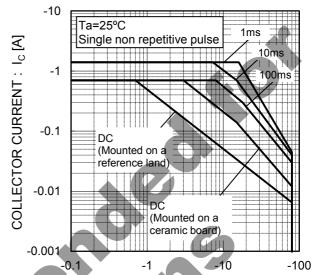


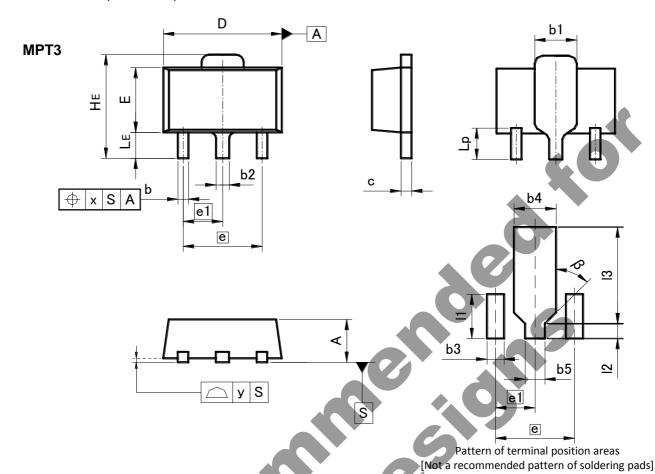
Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : V<sub>CE</sub> [V]



## ●Dimensions (Unit: mm)



		·			
DIM	MILIM	ETERS	INCHES		
DIIVI	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
C	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.118		
e1	1.	50	0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
Х	ı	0.15	1	0.006	
У		0.10	-	0.004	

DIM	MILIM	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
b3	-	0.65	ı	0.026	
b4	_	1.70	-	0.067	
b5		0.75	I	0.030	
l1	_	1.71	I	0.067	
12	_	0.58	I	0.023	
13	_	3.72	-	0.146	
β	45°		45	0	

Dimension in mm / inches

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